FAIRCHILD
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IGBT

SGP5N60RUF

Short Circuit Rated IGBT

General Description

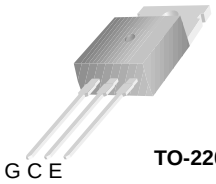
Fairchild's RUF series of Insulated Gate Bipolar Transistors (IGBTs) provide low conduction and switching losses as well as short circuit ruggedness. The RUF series is designed for applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short circuit ruggedness is a required feature.

Features

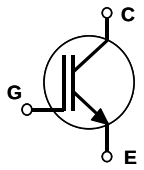
- Short circuit rated 10us @ T_C = 100°C, V_{GE} = 15V
- High speed switching
- Low saturation voltage : $V_{CE(sat)}$ = 2.2 V @ I_C = 5A
- High input impedance

Applications

AC & DC motor controls, general purpose inverters, robotics, and servo controls.



TO-220



Absolute Maximum Ratings

T_C = 25°C unless otherwise noted

Symbol	Description		SGP5N60RUF	Units
V_{CES}	Collector-Emitter Voltage		600	V
V_{GES}	Gate-Emitter Voltage		± 20	V
I_C	Collector Current	@ T_C = 25°C	8	A
	Collector Current	@ T_C = 100°C	5	A
$I_{CM\ (1)}$	Pulsed Collector Current		15	A
T_{SC}	Short Circuit Withstand Time	@ T_C = 100°C	10	us
P_D	Maximum Power Dissipation	@ T_C = 25°C	60	W
	Maximum Power Dissipation	@ T_C = 100°C	25	W
T_J	Operating Junction Temperature		-55 to +150	°C
T_{stg}	Storage Temperature Range		-55 to +150	°C
T_L	Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 Seconds		300	°C

Notes :
(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	--	2.0	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	--	62.5	°C/W

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Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
BV_{CES}	Collector-Emitter Breakdown Voltage	V_{GE} = 0V, I_C = 250uA	600	--	--	V
$\Delta B_{VCES}/\Delta T_J$	Temperature Coefficient of Breakdown Voltage	V_{GE} = 0V, I_C = 1mA	--	0.6	--	V/°C
I_{CES}	Collector Cut-Off Current	V_{CE} = V_{CES}, V_{GE} = 0V	--	--	250	uA
I_{GES}	G-E Leakage Current	V_{GE} = V_{GES}, V_{CE} = 0V	--	--	± 100	nA
On Characteristics						
$V_{GE(th)}$	G-E Threshold Voltage	I_C = 5mA, V_{CE} = V_{GE}	5.0	6.0	8.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	I_C = 5A, V_{GE} = 15V	--	2.2	2.8	V
		I_C = 8A, V_{GE} = 15V	--	2.5	--	V
Dynamic Characteristics						
C_{ies}	Input Capacitance	V_{CE} = 30V, V_{GE} = 0V, f = 1MHz	--	354	--	pF
C_{oes}	Output Capacitance		--	67	--	pF
C_{res}	Reverse Transfer Capacitance		--	14	--	pF
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{CC} = 300 V, I_C = 5A, R_G = 40Ω, V_{GE} = 15V, Inductive Load, T_C = 25°C	--	13	--	ns
t_r	Rise Time		--	24	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	34	50	ns
t_f	Fall Time		--	136	200	ns
E_{on}	Turn-On Switching Loss		--	88	--	uJ
E_{off}	Turn-Off Switching Loss		--	107	--	uJ
E_{ts}	Total Switching Loss		--	195	280	uJ
$t_{d(on)}$	Turn-On Delay Time	V_{CC} = 300 V, I_C = 5A, R_G = 40Ω, V_{GE} = 15V, Inductive Load, T_C = 125°C	--	13	--	ns
t_r	Rise Time		--	26	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	40	60	ns
t_f	Fall Time		--	250	350	ns
E_{on}	Turn-On Switching Loss		--	103	--	uJ
E_{off}	Turn-Off Switching Loss		--	220	--	uJ
E_{ts}	Total Switching Loss		--	323	--	uJ
T_{sc}	Short Circuit Withstand Time	V_{CC} = 300 V, V_{GE} = 15V @ T_C = 100°C	10	--	--	us
Q_g	Total Gate Charge	V_{CE} = 300 V, I_C = 5A, V_{GE} = 15V	--	16	24	nC
Q_{ge}	Gate-Emitter Charge		--	3	6	nC
Q_{gc}	Gate-Collector Charge		--	7	14	nC
L_e	Internal Emitter Inductance	Measured 5mm from PKG	--	7.5	--	nH

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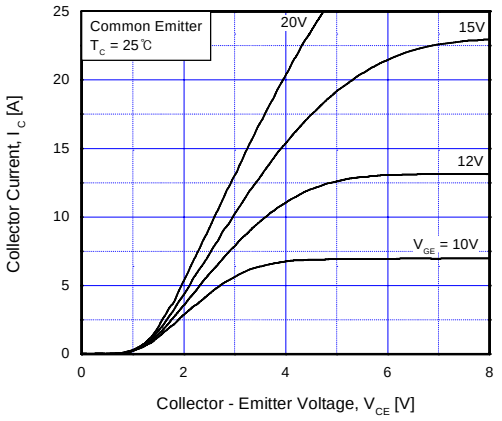


Fig 1. Typical Output Characteristics

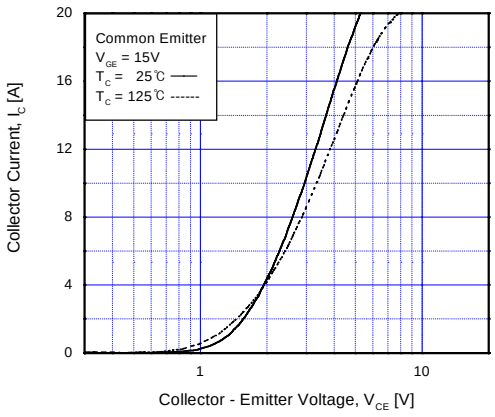


Fig 2. Typical Saturation Voltage Characteristics

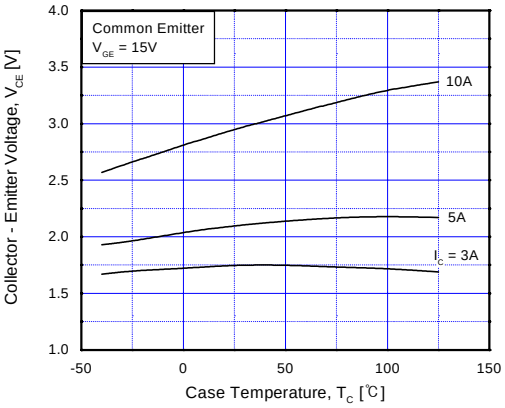


Fig 3. Saturation Voltage vs. Case Temperature at Variant Current Level

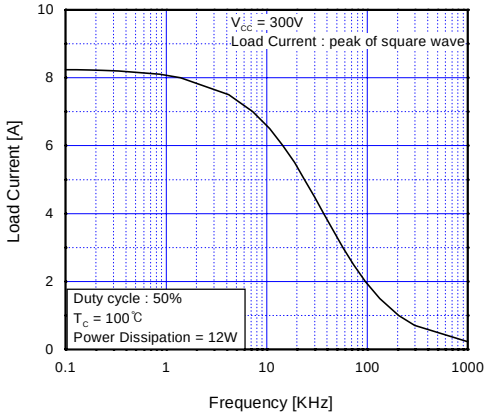


Fig 4. Load Current vs. Frequency

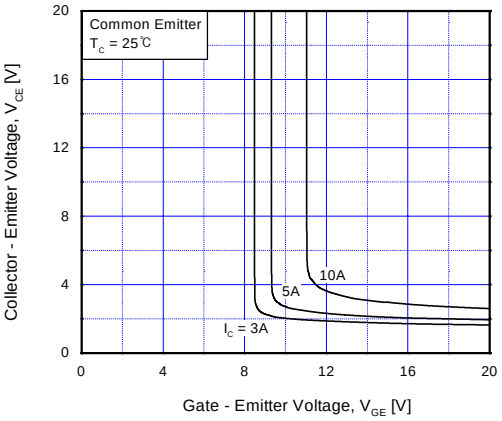


Fig 5. Saturation Voltage vs. V_{GE}

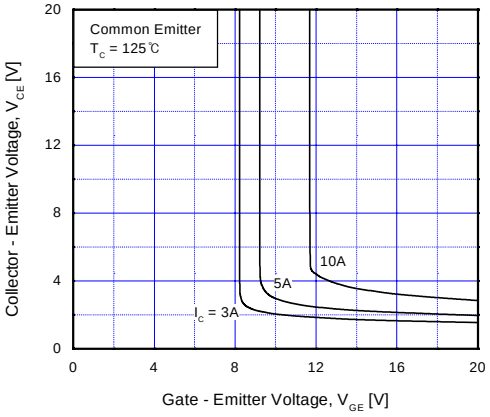


Fig 6. Saturation Voltage vs. V_{GE}

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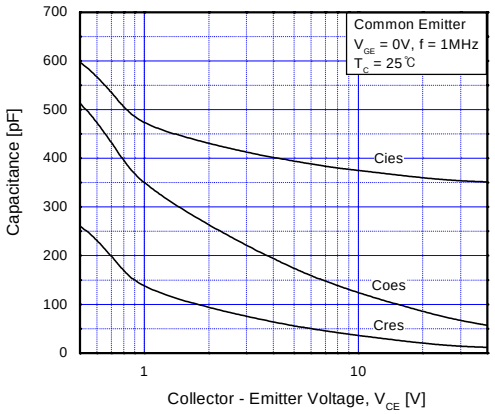


Fig 7. Capacitance Characteristics



Fig 8. Turn-On Characteristics vs. Gate Resistance

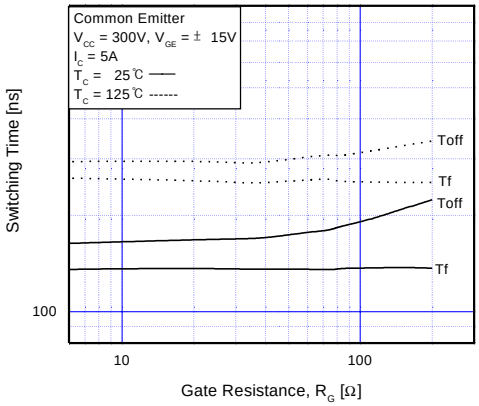


Fig 9. Turn-Off Characteristics vs. Gate Resistance

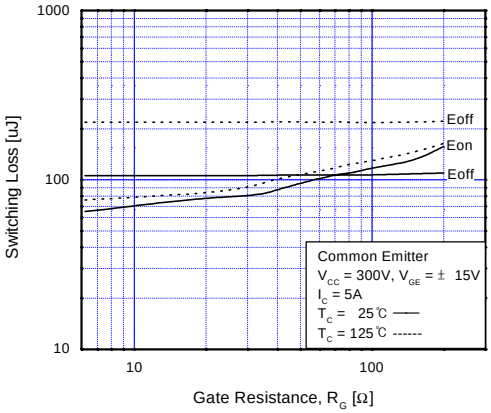


Fig 10. Switching Loss vs. Gate Resistance

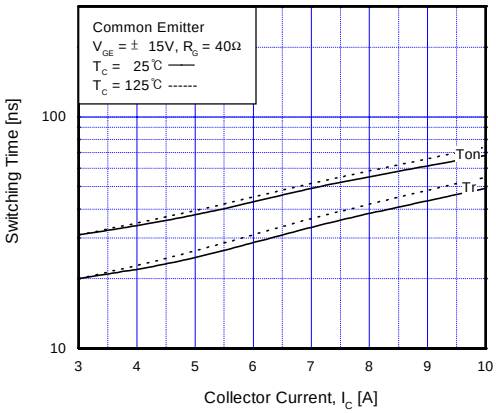


Fig 11. Turn-On Characteristics vs. Collector Current

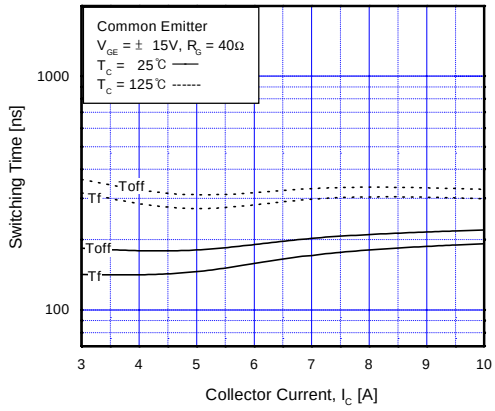


Fig 12. Turn-Off Characteristics vs. Collector Current

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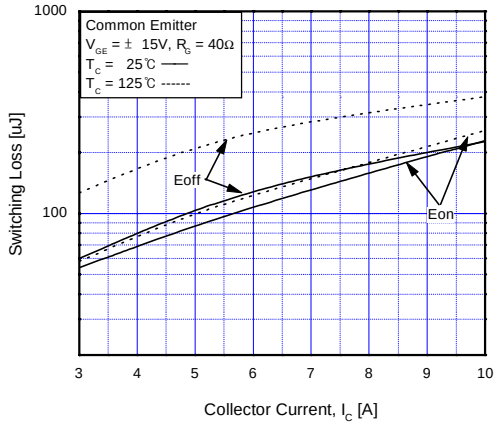


Fig 13. Switching Loss vs. Collector Current

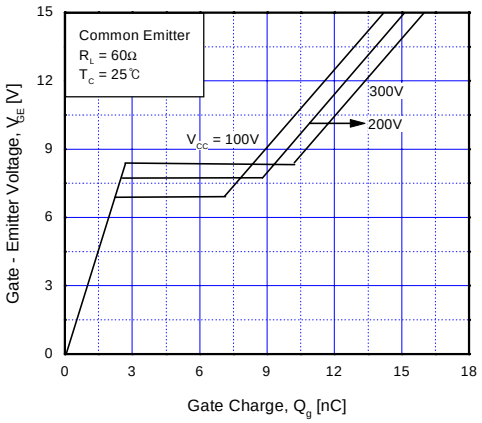


Fig 14. Gate Charge Characteristics

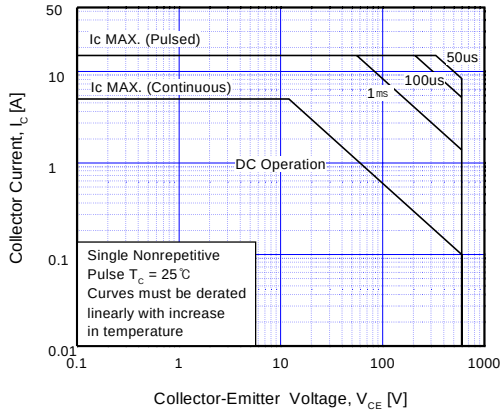


Fig 15. SOA Characteristic

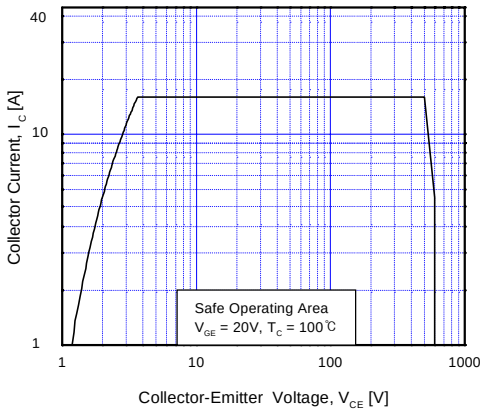


Fig 16. Turn-Off SOA Characteristics

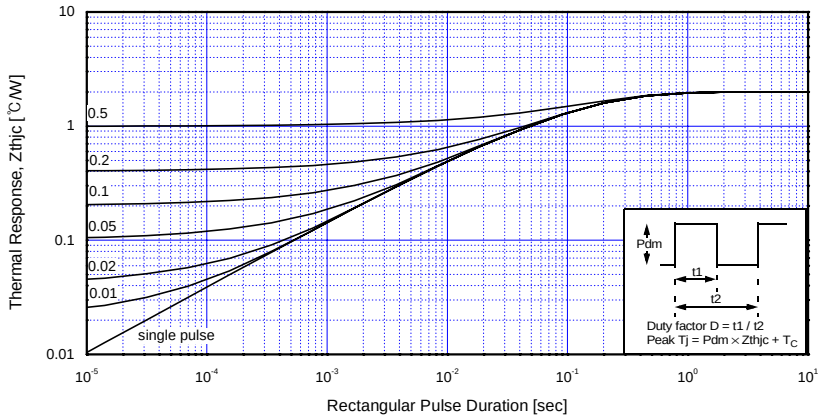
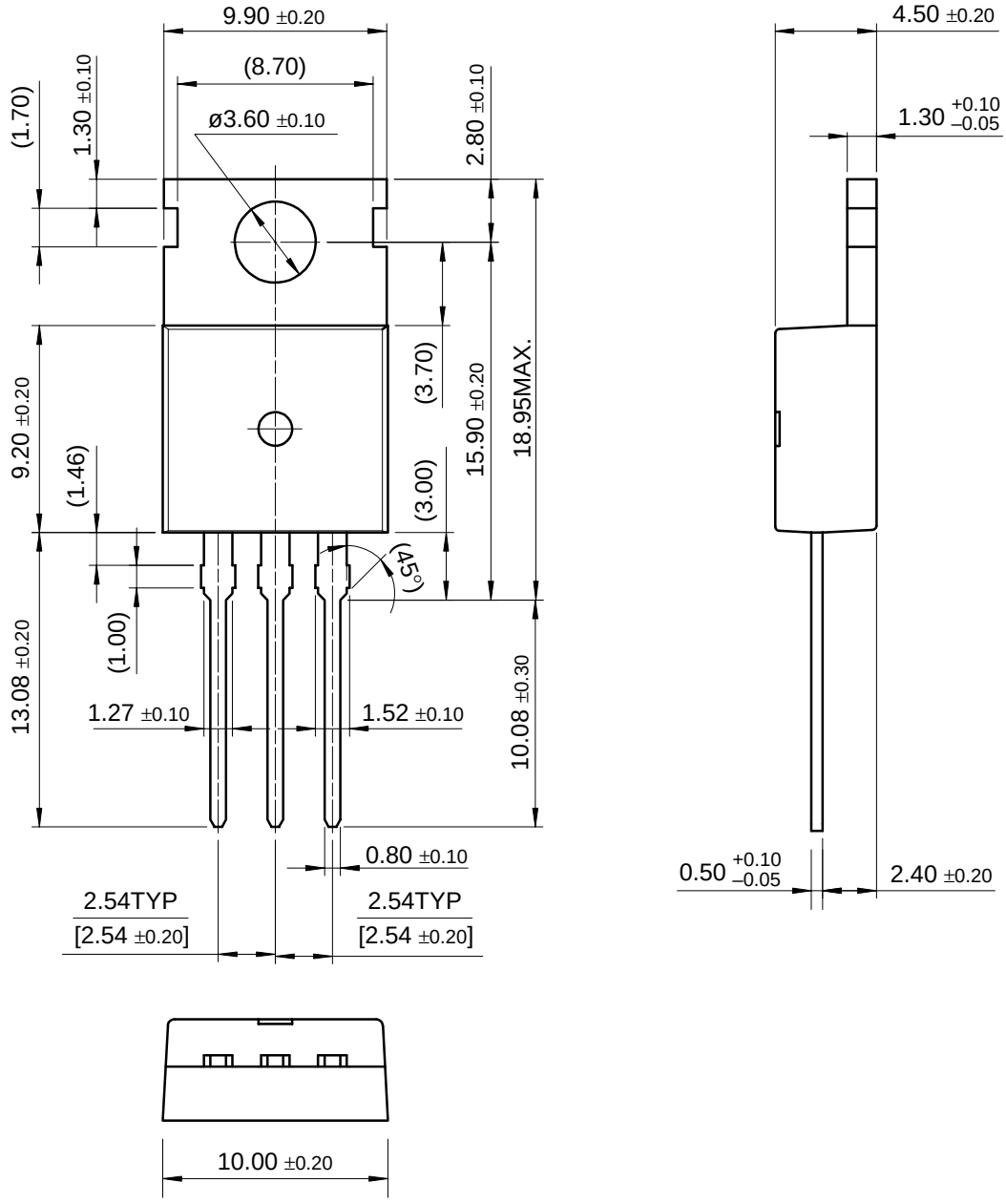


Fig 17. Transient Thermal Impedance of IGBT

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Package Dimension

TO-220



Dimensions in Millimeters

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SGP5N60RUF

Discrete, Short Circuit Rated IGBT

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General description

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Features

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- High Speed Switching
- Low Saturation Voltage : $V_{CE(sat)}$ = 2.2 V @ I_C = 5A
- High Input Impedance

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Applications

AC &DC Motor controls,General Purpose Inverters, Robotics, Servo Controls

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
SGP5N60RUFTU	Full Production	$1.28	TO-220	3	RAIL

* 1,000 piece Budgetary Pricing

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